# 1PS70SB14

# **Dual Schottky barrier diode**

17 December 2012

**Product data sheet** 

# 1. General description

Dual Planar Schottky barrier diode in series configuration with an integrated guard ring for stress protection, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

# 3. Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Reverse polarity protection

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
I <sub>F</sub>	forward current			-	-	200	mA	
V <sub>R</sub>	reverse voltage			-	-	30	V	
Per diode								
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C		-	-	400	mV	





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# 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode (diode1)	3	K1, A2
2	K2	cathode (diode2)		A1 F F K2
3	K1, A2	cathode (diode1) and anode (diode2)	1 2 SC-70 (SOT323)	aaa-004973

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package		
	Name	Description	Version
1PS70SB14	SC-70	plastic surface-mounted package; 3 leads	SOT323

# 7. Marking

Table 4. Marking codes

Type number	Marking code [1]
1PS70SB14	7%4

<sup>[1] % =</sup> placeholder for manufacturing site code

# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_R$	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> < 25 °C	-	200	mW
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	150	°C

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Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>stg</sub>	storage temperature		-65	150	°C

## 9. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

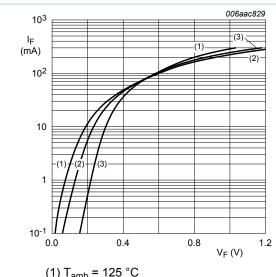
# 10. Characteristics

#### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						,
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 mA; T <sub>amb</sub> = 25 °C	-	-	240	mV
		I <sub>F</sub> = 1 mA; T <sub>amb</sub> = 25 °C	-	-	320	mV
		I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	-	400	mV
		I <sub>F</sub> = 30 mA; T <sub>amb</sub> = 25 °C	-	-	500	mV
		I <sub>F</sub> = 100 mA; T <sub>amb</sub> = 25 °C	-	-	800	mV
I <sub>R</sub>	reverse current	$V_R$ = 25 V; pulsed; $t_p$ = 300 µs; $\delta$ = 0.02 ; $T_{amb}$ = 25 °C	-	-	2	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	10	pF

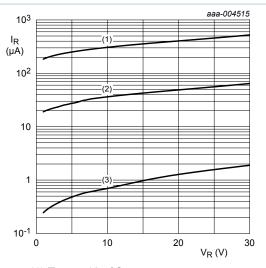
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#### **Dual Schottky barrier diode**



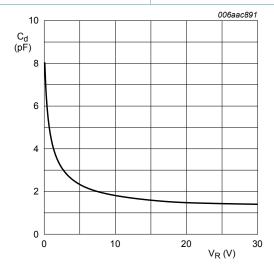
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig. 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- $(3) T_{amb} = 25 °C$

Fig. 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \,^{\circ}C; f = 1 \, MHz$ 

Diode capacitance as a function of reverse voltage; typical values

## 11. Test information

## 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

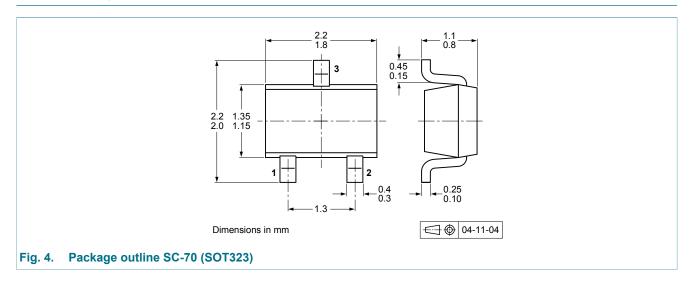
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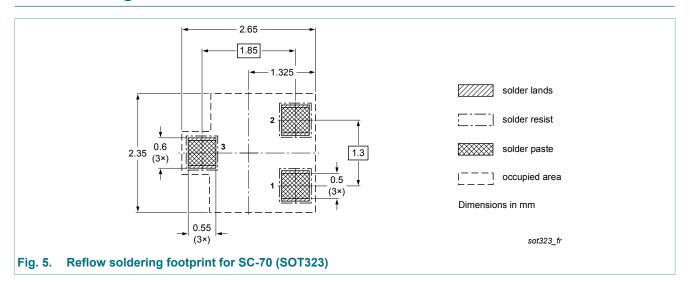
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# 12. Package outline

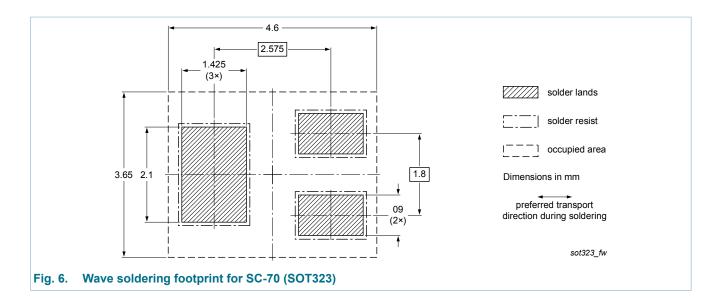


# 13. Soldering



**Product data sheet** 

## **Dual Schottky barrier diode**



# 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS70SB14 v.2	20121217	Product data sheet	-	1PS70SB10_14_15_16 v.1
Modifications:	of NXP Semiconduct Legal texts have be Sections 1 to 3 upde Section 4 "Quick red Section 6 "Ordering Section 7 "Marking" Table 5 "Limiting va Figues 1, 2 and 3 updes	en adapted to the new co ated ference data" added information" added updated lues": ambient temperatu pdated ormation" added ed by minimized package ng" added	ompany name where app re T <sub>amb</sub> and junction tem	ropriate.
1PS70SB10_14_15_16 v.1	19990426	Product data sheet	-	-

**Product data sheet** 

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#### **Dual Schottky barrier diode**

## 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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